


 Cite this: *RSC Adv.*, 2023, **13**, 3592

Optical transitions and radiative properties of green emitting Ho³⁺:YVO₄ phosphor

 Vijay Singh,^a M. Seshadri,^b Deepak Taikar,^c S. J. Dhoble^d and R. S. Yadav^e

The Ho³⁺-doped YVO₄ phosphors were successfully prepared *via* a sol-gel process in which citric acid was used as a chelating agent. X-ray diffraction (XRD) confirmed the effective inclusion of Ho³⁺ ions into the host matrix with the formation of single phase YVO₄. The surface morphology was observed using SEM, the results of which showed a grain growth propensity and the agglomeration of prepared phosphors. The V–O (VO₄³⁻) vibration mode was analyzed through Fourier transform infrared (FTIR) spectra. The spectroscopic properties were reported through UV-vis-NIR diffuse reflectance and photoluminescence (PL) spectra. The Judd–Ofelt (J–O) intensity parameters $\Omega_2 = 0.03 \times 10^{-20} \text{ cm}^2$, $\Omega_4 = 0.22 \times 10^{-20} \text{ cm}^2$, and $\Omega_6 = 0.23 \times 10^{-20} \text{ cm}^2$ obtained for the Y_{0.97}VO₄:0.03Ho³⁺ phosphors were used to obtain the total transition probabilities (A_T), radiative lifetimes (τ_{rad}) and branching ratios (β) for the certain transitions of Ho³⁺ ions. Under 310 nm UV excitation, the visible emission spectra were measured, and an intense emission was observed around 541 nm (green region) for all the samples. The emission cross-section $\sigma_P(\lambda)$ was $3.22 \times 10^{-21} \text{ cm}^2$ and the branching ratio (β) was 0.816; these were investigated to capture the optimal concentration of the Y_{0.97}VO₄:0.03Ho³⁺ phosphor. The estimated color coordinates were observed in the green region of CIE diagram. Ultimately, the superior properties ($\sigma_P(\lambda)$, β , and color purity) of Y_{0.97}VO₄:0.03Ho³⁺ phosphor may make it suitable for green emitting devices.

 Received 6th October 2022
 Accepted 20th November 2022

DOI: 10.1039/d2ra06287a

rsc.li/rsc-advances

1. Introduction

Recently, the zircon structured orthovanadate (AVO₄, A = trivalent metal ion) has attracted substantial research attention because of its applicability in a wide variety of areas.¹ This material is not only used as a luminescent host material but has also been used in diverse applications in the fields of gas sensing, high power lasers, fuel cell anodes, and counter electrodes in electrochromic devices.^{2–4} Yttrium vanadate (YVO₄) is a well-recognized host lattice for rare-earth (RE) activators from the family of AVO₄. YVO₄ shows excellent thermal, mechanical, and optical properties, and it exhibits wide absorption in the UV region; therefore, RE doped phosphors are widely used for optoelectronic application alongwith biosensors and laser devices.^{5–12} YVO₄ shows high birefringence and can be used as a polarizer in the infrared (IR) region.¹³ YVO₄ is also a good up-conversion host due to its low phonon energy ($\sim 880 \text{ cm}^{-1}$). Many studies have examined up-conversion luminescence in RE³⁺-doped and co-doped YVO₄ phosphors.^{14–17} YVO₄:Nd³⁺

performs better than YAG:Nd³⁺, and it is therefore a good laser excitable host crystal for Nd³⁺ ions, and has shown remarkable applicability in laser-diode pumped micro lasers.^{18–21}

At present, to conquer multiple color tunability, the phosphor materials are used in energy conversion and materials technology. Due to its efficient energy conversion, the high color purity and thermal stability of Eu³⁺-doped YVO₄ make it a promising red phosphor for use in a wide range of applications in luminescence and display devices, such as fluorescent lamps, cathode ray tubes, plasma display panels, *etc.*^{22–30} Foka *et al.*³¹ synthesized Dy³⁺-doped YVO₄ phosphor *via* the combustion route and reported white emission with excitation in the UV region. Liu *et al.*³² synthesized YVO₄:Ln³⁺ (Ln = Eu, Sm, Dy) *via* the microwave heating method and reported its morphology and photoluminescence (PL) results. Xu *et al.*³³ studied the effects of organic additives on the shape and morphology of RE³⁺-doped YVO₄ phosphors synthesized *via* a hydrothermal method. They have found remarkable results, which can be used for tunability in the display panels. Their PL study indicates an efficient multicolor emission that can be useful in lasers and displays related to the optoelectronic devices. Huang *et al.*³⁴ synthesized (Bi³⁺, RE³⁺) co-doped YVO₄ phosphor by a solid-state reaction technique and reported that the phosphors could improve the efficiency of the power conversion of dye-sensitized and crystalline silicon (c-Si) solar cells. The energy transfer between single and triply doped RE³⁺ ions in the YVO₄ host and its luminescence property have

^aDepartment of Chemical Engineering, Konkuk University, Seoul, 05029, Republic of Korea. E-mail: vijayjiin2006@yahoo.com

^bDepartment of Physics, KG Reddy College of Engineering and Technology, Hyderabad-501504, India

^cDepartment of Physics, Shri Lemdeo Patil Mahavidyalaya, Mandhal, 441210, India

^dDepartment of Physics, R.T.M. Nagpur University, Nagpur, 440033, India

^eDepartment of Zoology, Institute of Science, Banaras Hindu University, Varanasi, 221005, India


recently been studied by Medvedev *et al.*³⁵ Moreover, all the rare earth ions and their doped systems of the phosphors with Ho^{3+} ion serve as good activators due to energy transfer and reflecting the multiple color emission. Zhou *et al.*³⁶ studied the PL property of red emitting $\text{YVO}_4:\text{Pr}^{3+}$ phosphor, which is considered to be a good candidate for optical thermal sensing applications. YVO_4 phosphors have been synthesized through various synthesis methods, such as co-precipitation,³⁷ solution combustion,³⁸ solid state reaction,³⁴ microwave heating,³² sol-gel,^{39,40} microemulsions,⁴¹ solvothermal,⁴² ultrasonic,⁴³ and spray pyrolysis methods.⁴⁴ The $\text{YVO}_4:(\text{Ho}^{3+}, \text{Yb}^{3+})$ phosphors synthesized by different synthesis method and their effect on luminescence have recently been studied.³⁹ The study indicates that the $\text{YVO}_4:(\text{Ho}^{3+}, \text{Yb}^{3+})$ phosphor prepared by sol-gel method exhibit better optical properties than the phosphor synthesized by the combustion and solid state reaction methods.

In the present work, most notably, we have successfully synthesized trivalent holmium (Ho^{3+})-doped YVO_4 phosphors with different doping concentrations. The samples were characterized in terms of their physical and radiative properties by using X-ray diffraction (XRD), scanning electron microscopy (SEM), Fourier transform infrared (FTIR) spectroscopy, ultraviolet-visible (UV-vis) spectrometry, and photoluminescence (PL) techniques.

2. Materials preparation and analysis

Phosphor materials of $\text{Y}_{1-x}\text{VO}_4:x\text{Ho}^{3+}$ ($x = 0.01, 0.03, 0.05, 0.07, 0.09, 0.11$) were prepared through the sol-gel method. The details of the sample composition and the starting materials along with required weights are given in Table 1. The appropriate amounts of $\text{Y}(\text{NO}_3)_3 \cdot 6\text{H}_2\text{O}$, NH_4VO_3 , $\text{Ho}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$, and citric acid (chelating agent for the metal ions) were weighed and added into a 150 ml glass beaker with 10 ml deionized water. The prepared solution was stirred for 1 hour to ensure uniform homogeneity. Next, the solution was placed in a hot oven until it was completely dried. The dried gels were heated in air at 400 °C for upto 2 hours. The preheated powder samples were ground and again heated in air at 800 °C for 2 hours to acquire the final samples. Fig. 1 shows a flow chart of the synthesis method.

The phase of prepared powders was identified using a RIGAKU (Miniflex-II) XRD spectrometer with $\text{CuK}\alpha$ light radiation as X-ray. FTIR spectrum in the 4000–400 cm^{-1} range was obtained on a Thermo Fisher Nicolet (6700 FT-IR)

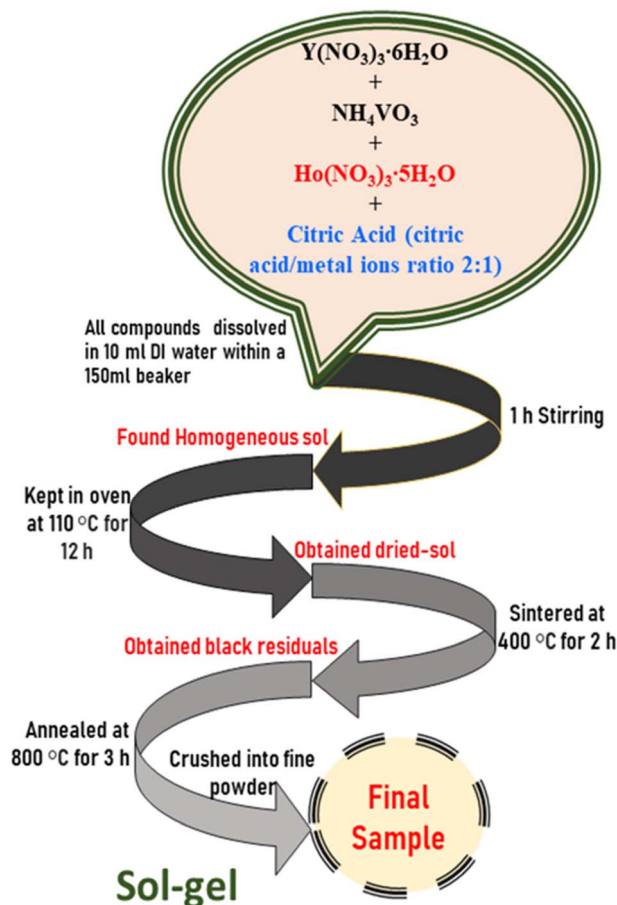


Fig. 1 Flow chart of synthesis method of $\text{Y}_{1-x}\text{VO}_4:x\text{Ho}^{3+}$ phosphors.

spectrometer utilizing KBr pellets. The sample surface morphology was imaged using a S-3400, SEM (Hitachi, Japan). The diffuse reflection spectrum was captured with a UV-VIS-NIR (Cary-5000) spectrophotometer. PL characterizations were carried out at room temperature using a RF-5301PC, Shimadzu, fluorescence spectrophotometer with a Xenon flash lamp as an excitation source.

3. Results and discussion

Fig. 2 shows the crystal structure of the YVO_4 compound with different orientations. YVO_4 is (zircon type structure) crystallized in the tetragonal $I4_1/amd$ space group. In this structure,

Table 1 Detailed information of sample and weight of the required starting materials

| Samples | Base materials | | | |
|---|----------------|-------------|---------------|--------------|
| $\text{Y}_{0.99}\text{VO}_4:0.01\text{Ho}^{3+}$ | Y = 0.7583g | V = 0.2338g | C.A = 1.5368g | Ho = 0.0176g |
| $\text{Y}_{0.97}\text{VO}_4:0.03\text{Ho}^{3+}$ | Y = 0.7430g | V = 0.2338g | C.A = 1.5368g | Ho = 0.0592g |
| $\text{Y}_{0.95}\text{VO}_4:0.05\text{Ho}^{3+}$ | Y = 0.7277g | V = 0.2338g | C.A = 1.5368g | Ho = 0.0882g |
| $\text{Y}_{0.93}\text{VO}_4:0.07\text{Ho}^{3+}$ | Y = 0.7123g | V = 0.2338g | C.A = 1.5368g | Ho = 0.1243g |
| $\text{Y}_{0.91}\text{VO}_4:0.09\text{Ho}^{3+}$ | Y = 0.6970g | V = 0.2338g | C.A = 1.5368g | Ho = 0.1578g |
| $\text{Y}_{0.89}\text{VO}_4:0.11\text{Ho}^{3+}$ | Y = 0.6817g | V = 0.2338g | C.A = 1.5368g | Ho = 0.1940g |

Y = $\text{Y}(\text{NO}_3)_3 \cdot 6\text{H}_2\text{O}$, V = NH_4VO_3 , C.A = citric acid, Ho = $\text{Ho}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$



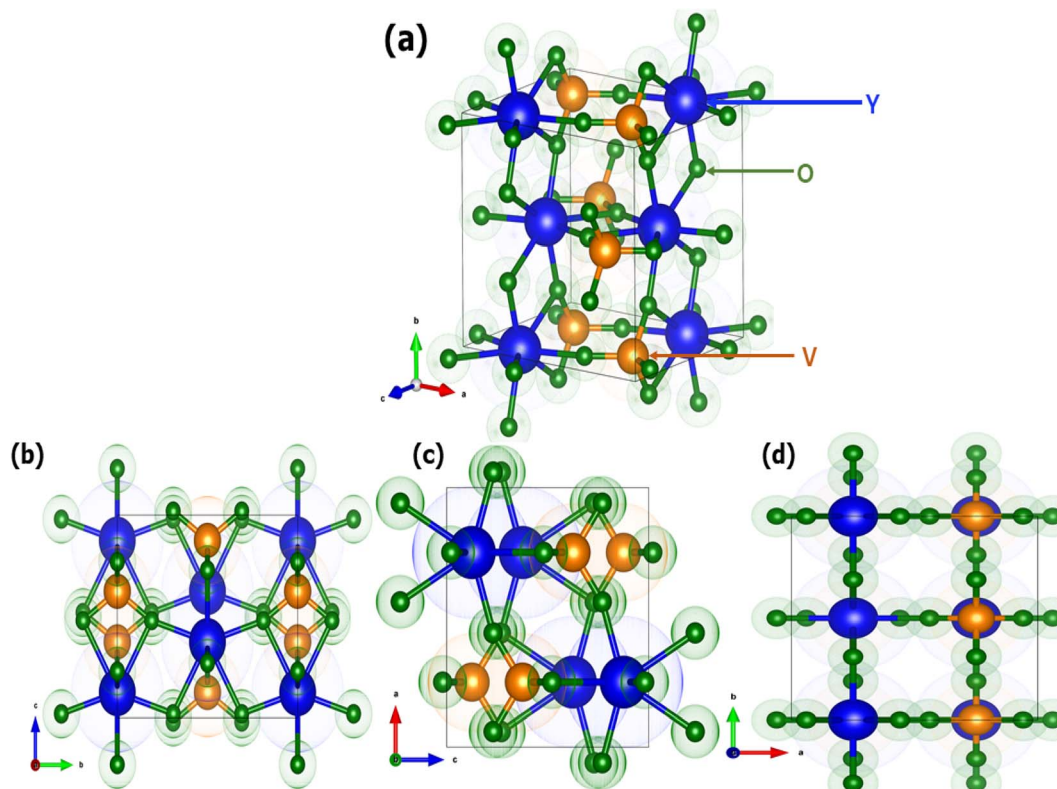


Fig. 2 Crystal structure of YVO_4 (a) standard orientation and (b–d) three different orientations 100, 010, and 001.

Y^{3+} atom has D_{2d} site symmetry and is bonded in 8-coordinate geometry to eight equivalent O^{2-} atoms to form an anti-prism. Out of these eight Y–O bonds, four have shorter bond lengths (2.33 Å) whereas the other four have longer bond lengths (2.45 Å). The V^{5+} atom is bonded with four equivalent O^{2-} atoms to form VO_4^{3-} tetrahedra which share edges with YO_8 dodecahedrons, as shown in Fig. 2. All V–O bond lengths are 1.74 Å. The

O^{2-} atom is bonded with two equivalent Y^{3+} atoms and one V^{5+} atom.^{45,46} Fig. 3 shows the observed XRD patterns of the YVO_4 phosphors produced through the sol-gel technique. The observed XRD patterns are counterpart with the standard card of JCPDF 70-1281. No miscellaneous or additional peak is observed in all the XRD patterns, thus suggesting a single-phase material and indicates that the crystal structure of host matrix does not change with the addition of Ho^{3+} ion. The ionic radius of Ho^{3+} ($r = 0.89$ Å) was found to be well matched with ionic radius of Y^{3+} ($r = 0.9$ Å, CN = 8), thus indicates that the Ho^{3+} is successfully incorporated at the Y^{3+} sites. The XRD pattern shows that the prepared YVO_4 crystallizes in the tetragonal $I4_1/amd$ space group along with cell parameters $a = 7.120$ Å, $c = 6.289$ Å, and volume = 318.82 Å³. The average crystallite size can be determined using the formula,

$$D = 0.9\lambda/\beta \cos \theta \quad (1)$$

here, λ (1.540598 Å) is the wavelength of X-ray radiation, and the diffraction angle of Bragg's (θ) and Full width at half maxima (FWHM) is denoted by β . The average crystallite size of the phosphor samples was within the 20–30 nm range.

Fig. 4 presents SEM images of the synthesized $\text{Y}_{0.97}\text{VO}_4:0.03\text{Ho}^{3+}$ phosphor. The inhomogeneous morphology and large grain size are observed in the SEM images. SEM images reveal that the phosphor particles morphologies are not uniform, they also show that the phosphor particles are irregular and agglomerated Fig. 4(b) shows an enlarged view of the

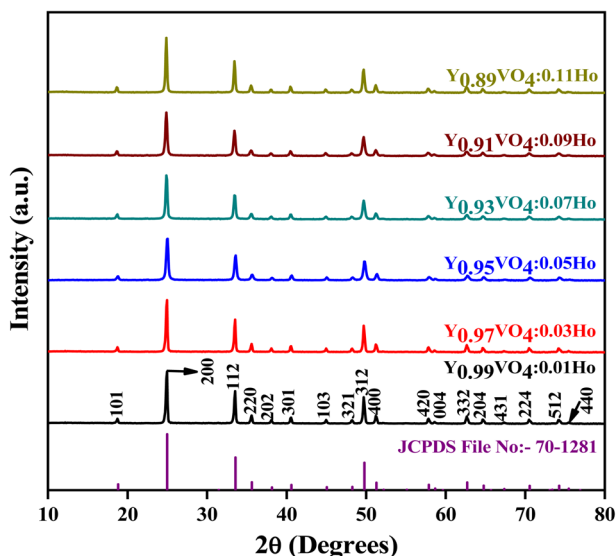


Fig. 3 Powder XRD patterns of $\text{Y}_{1-x}\text{VO}_4:x\text{Ho}^{3+}$ phosphors.



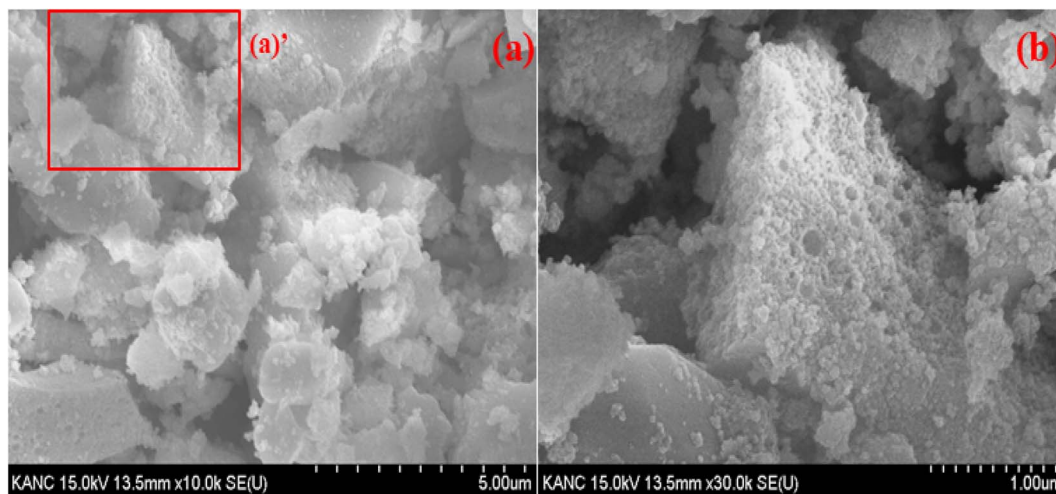


Fig. 4 (a) SEM image of $Y_{0.97}VO_4:0.03Ho^{3+}$ phosphor and (b) enlarged view of zone (a)'.

“zone (a)” of Fig. 4(a), wherein the sample consists of voids, and pores that are most likely due to the evolution of large amount of gases during the process of sintering. The grain size distribution is broad, and the average particles size ranges from 100 nm to 500 nm for the $Y_{0.97}VO_4:0.03Ho^{3+}$ phosphor. These characteristics suggest that the optical properties are suitable for the industrial use.

Fig. 5 reveals the FTIR spectrum of $Y_{0.97}VO_4:0.03Ho^{3+}$ phosphor, which is used to analyze the chemical structure and presence of the functional groups associated with the crystal. The intense band situated at 814 cm^{-1} is remarkably matched with the characteristic vibrational modes of the V–O group of the tetrahedral structure of VO_4^{3-} group.⁴⁷ The weak band occurring at 450 cm^{-1} is attributable to the Y–O group of structural vibrations. The very weak bands observed between 1100 to 1400 cm^{-1} is due to the presence of C–O and nitrate groups alongwith the band between 1400 to 1500 cm^{-1}

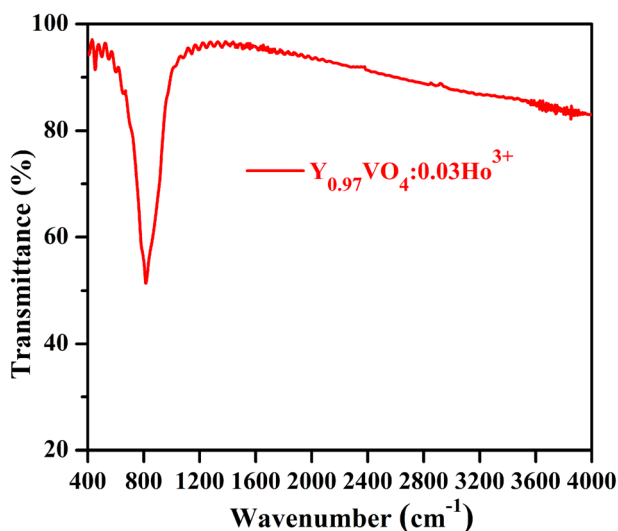


Fig. 5 FT-IR spectrum of $Y_{0.97}VO_4:0.03Ho^{3+}$ phosphor.

associated with the vibrations of carboxylate anions of the citric acid. A very weak band observed at 2350 cm^{-1} corresponds to the asymmetrical stretching modes of CO_2 .¹⁷ Some very weak bands beyond 3500 cm^{-1} are also assigned to the water molecules present on the sample surface.

Fig. 6(a) depicts the diffuse reflectance spectrum of $Y_{0.97}VO_4:0.03Ho^{3+}$ phosphor. The sharp peaks observed around 421, 458, 469, 478, 489, 544, and 651 nm are associated with the transitions from the ground state of 5I_8 to the 5G_5 , $^5G_6 + ^5F_1$, 3K_8 , 5F_2 , 5F_3 , $^5F_4 + ^5S_2$, and 5F_5 excited states of Ho^{3+} ions, respectively.^{48,49} The extracted absorption coefficient ($\alpha\text{ cm}^{-1}$) with the Kubelka–Munk function can be written as:⁴⁸

$$F(R) = \frac{(1 - R)^2}{2R} = \alpha \quad (2)$$

where R is the sample reflectance. The extracted optical coefficient ($\alpha\text{ cm}^{-1}$) can be calculated by using relation (2). The optical band gap (E_g) for the $Y_{0.97}VO_4:0.03Ho^{3+}$ phosphor can be estimated using the Tauc relation:⁴⁸

$$F(R) hv \approx A(hv - E_g)^n \quad (3)$$

where A is a constant, $F(R)$ is the absorption coefficient, hv is the energy of the photon, and $n = 1/2$ (and/or 2) for allowed direct (and/or indirect) transition. Fig. 6(b and c) represents the variation between the $(F(R) * hv)^n$ and hv (eV). By generalizing the linear region of the plot to $(F(R) * hv)^2 = 0$ and $(F(R) * hv)^{1/2} = 0$, the energy bandgaps for the indirect and direct allowed transitions are found to be $3.30 \pm 0.24\text{ eV}$ and $3.59 \pm 0.38\text{ eV}$, respectively for the Ho^{3+} doped YVO_4 phosphor.

The Judd–Ofelt theory^{49,50} is used to characterize the spectroscopic properties of rare earth doped host matrix, for which details are available elsewhere.⁵¹ Therefore, these remarkable outcomes explain the existence theory of the material properties. The doped YVO_4 phosphor is an excellent host matrix for rare earth doping to support the energy conversion to the Ho^{3+} ions. According to Judd–Ofelt theory, the oscillator strengths



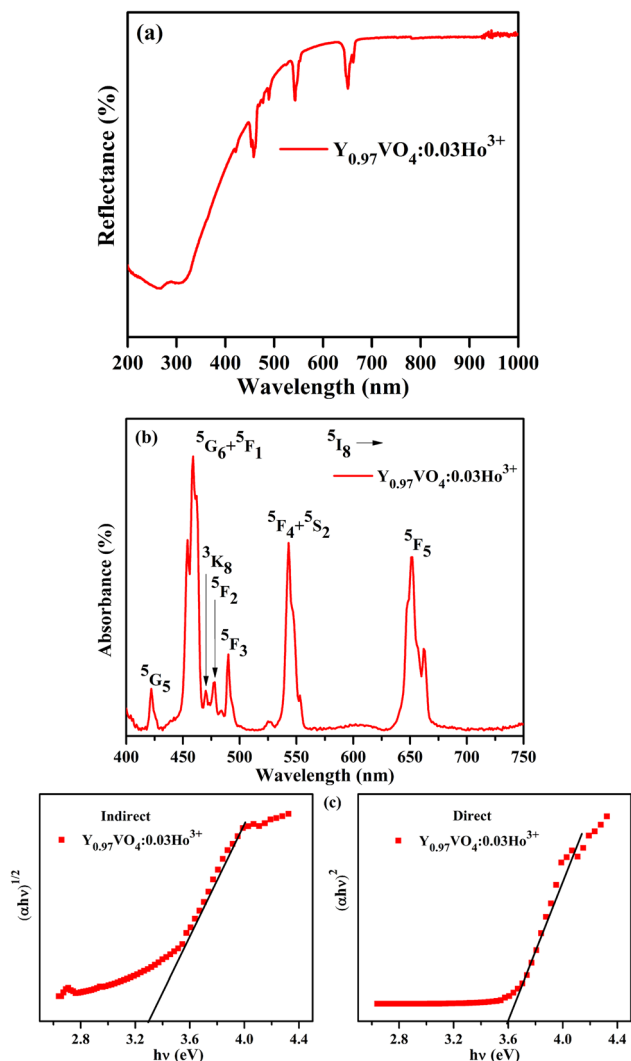


Fig. 6 (a) Diffuse reflection spectrum, (b) absorption spectrum and (c) plots of indirect and direct bandgaps of $\text{Y}_{0.97}\text{VO}_4:0.03\text{Ho}^{3+}$ phosphor.

(f_{cal}) of an electric dipole multiplets ($J \rightarrow J'$) of Ho^{3+} can be expressed as,

$$f_{\text{cal}} = \frac{8\pi^2 m c \cdot (n^2 + 2)^2}{3h(2J + 1)\lambda \cdot 9n} \times \sum_{\lambda=2,4,6} \Omega_{\lambda} |\langle (SL)J \| U^{(\lambda)} \| (S'L')J \rangle|^2 \quad (4)$$

where Ω_{λ} ($\lambda = 2, 4 \& 6$) are the J–O intensity parameters and $U^{(\lambda)}$ are the doubly diminished matrix elements taken from ref. 52, and these tensor operators are independent of the host. The measured oscillator strengths (f_{meas}) for the observed absorption bands are calculated using,⁵³

$$f_{\text{meas}} = \frac{m c^2}{\pi e^2 \lambda^2 N} \times \frac{2.303}{d} \int \text{OD}(\lambda) d\lambda \quad (5)$$

where N is the ion concentration (ions/cm³), d is the sample thickness, and $\text{OD}(\lambda)$ is the optical density as a function of wavelength. Table 2 reports the oscillator strength (f_{meas} and f_{cal}) for $\text{Ho}^{3+}:\text{YVO}_4$ phosphor along with the other hosts. Ω_{λ}

parameters are evaluated through a standard least square fitting method with the known oscillator strengths of the absorption transitions. The magnitude of root mean square (δ_{rms}) provides information on the quality of the fit, and its formula is,

$$\delta_{\text{rms}} = [(f_{\text{meas}} - f_{\text{cal}})^2 / (p - q)]^{1/2} \quad (6)$$

where p and q are the number of transitions employed to the fit and the required fixed parameters, respectively. The observed small r.m.s. deviation (see Table 2) indicates the authenticity of J–O theory.

Table 3 shows the J–O intensity parameters (Ω_2 , Ω_4 , and Ω_6) of various host matrices. It is well known that the Ω_2 parameter is associated with the covalency of the Ho–O bond, and that the Ω_4 and Ω_6 intensity parameters are related to the bulk properties of the host matrix. From Table 3, it can be seen that the magnitude of Ω_2 in YVO_4 phosphor is comparable with that in the YAG ($\text{Y}_3\text{Al}_5\text{O}_{10}$) and lower than those in the other reported host matrices, thus indicates lower covalency around the Ho–O bond. Using the J–O intensity parameter, Ω_{λ} values; the transition probabilities for the radiative transitions (A_{rad}), excited states of radiative lifetimes (τ_{R}), and branching ratios (β) are calculated for the $\text{Ho}^{3+}:\text{YVO}_4$ phosphor using the formula,⁵³

$$A_{\text{rad}} = \frac{64\pi^4 \nu^3}{3hc^3(2J + 1)} \frac{n(n^2 + 1)^2}{9} \sum_{\lambda=2,4,6} \Omega_{\lambda} |\langle (SL)J \| U^{(\lambda)} \| (S'L')J \rangle|^2 \quad (7)$$

$$\tau_{\text{R}} = 1/A_{\text{T}} \quad (8)$$

$$\beta = A_{\text{rad}}/A_{\text{T}} \quad (9)$$

where A_{T} is the total radiative transition probability and is estimated by the sum of the A_{rad} . Table 4 represents total radiative transition probabilities (A_{T}), radiative lifetime (τ_{rad}) of certain excited states, and branching ratios for certain emission transitions of Ho^{3+} ions in YVO_4 phosphor. From Table 4, it can be seen that the magnitudes of radiative lifetime for the excited levels are in the order of ${}^3\text{K}_8 > {}^5\text{F}_5 > {}^5\text{F}_2 > {}^5\text{F}_3 > {}^5\text{F}_4 > {}^3\text{H}_5 > {}^5\text{G}_6$. The observed magnitudes of the radiative lifetimes of $\text{Ho}^{3+}:\text{YVO}_4$ are comparatively higher than those of the reported Ho^{3+} doped hosts: CaScO_4 ,⁵⁴ SrLaGaO_4 ,⁵⁵ Y_2O_3 ,⁵⁸ and Lu_2SiO_5 ,⁶⁰ respectively.

Fig. 7(a) represents the PL excitation spectra of $\text{Y}_{1-x}\text{VO}_4:x\text{Ho}^{3+}$ phosphor materials in the wavelength range from 220 to 530 nm that are obtained by observing the emission wavelength at 541 nm. The broad excitation band appearing between the ~220 and 350 nm wavelength range is the charge transfer (CT) transition (at 310 nm) from the oxygen ligand (O^{2-}) to the central vanadium atom (V^{5+}) within the VO_4^{3-} group, as well as the CT band (at 270 nm) from O^{2-} to Ho^{3+} ions.^{32,44,61,62} Some sharp excitation peaks appear at ~360, 420, 450, 456, 468, 475, and 487 nm, and these are attributed to the transitions from the ground state ${}^5\text{I}_8$ to ${}^3\text{H}_6$, ${}^5\text{G}_5$, ${}^5\text{F}_1$, ${}^5\text{G}_6$, ${}^3\text{K}_8$, ${}^5\text{F}_2$, and ${}^5\text{F}_3$ of the excited states of Ho^{3+} ions, respectively.⁶³ Among all these observed sharp peaks, the 456 nm peak is the most prominent.



Table 2 Measured and calculated oscillator strengths (f_{exp} and f_{cal}) for Ho^{3+} ions in the $\text{Y}_{0.97}\text{VO}_4:0.03\text{Ho}^{3+}$ phosphor

| [$S'L'J'$] manifold | λ (nm) | $\text{Y}_{0.97}\text{VO}_4:0.03\text{Ho}^{3+}$ ^a | | CaSc ₂ O ₄ (ref. 54) | SrLaGaO ₄ (ref. 55) | Y ₃ Al ₅ O ₁₀ (ref. 56) |
|---|----------------|--|---------------------------------|--|----------------------------------|--|
| | | $f_{\text{meas}} \times 10^{-6}$ | $f_{\text{cal}} \times 10^{-6}$ | $f_{\text{meas}} \times 10^{-6}$ | $f_{\text{meas}} \times 10^{-6}$ | $f_{\text{meas}} \times 10^{-6}$ |
| ⁵ G ₅ | 421 | 0.05 | 0.35 | 1.11 | — | 3.61 |
| ⁵ G ₆ + ⁵ F ₁ | 458 | 0.73 | 0.74 | 5.47 | 20.7 | 5.83 |
| ³ K ₈ | 469 | 0.01 | 0.11 | — | 0.29 | 4.03 |
| ⁵ F ₂ | 478 | 0.03 | 0.11 | — | 0.10 | — |
| ⁵ F ₃ | 489 | 0.09 | 0.20 | — | 0.92 | — |
| ⁵ S ₂ + ⁵ F ₄ | 544 | 0.48 | 0.62 | 1.73 | 3.86 | 4.72 |
| ⁵ F ₅ | 651 | 0.68 | 0.44 | 2.12 | 3.37 | 3.86 |
| δ_{rms} | 0.45 | — | — | 0.14 | 5.36 | 0.89 |

^a Present work.

Table 3 Judd–Ofelt intensity parameters (Ω_λ , $\lambda = 2, 4 \& 6$) for Ho^{3+} ions in the host matrices

| Host matrix | Ω_2 | Ω_4 | Ω_6 |
|--|------------|------------|------------|
| $\text{Y}_{0.97}\text{VO}_4:0.03\text{Ho}^{3+}$ ^a | 0.03 | 0.22 | 0.23 |
| CaSc ₂ O ₄ (ref. 54) | 3.78 | 5.17 | 1.92 |
| SrLaGaO ₄ (ref. 55) | 1.25 | 0.42 | 1.80 |
| Y ₃ Al ₅ O ₁₀ (ref. 56) | 0.04 | 2.67 | 1.89 |
| SrLaGa ₃ O ₇ (ref. 57) | 2.23 | 0.85 | 1.81 |
| Y ₂ O ₃ (ref. 58) | 0.45 | 0.59 | 0.32 |
| LiYF ₄ (ref. 59) | 1.16 | 2.24 | 2.09 |

^a Present work.

Table 4 Radiative properties of certain excited levels/transitions of Ho^{3+} ions in the $\text{Y}_{0.97}\text{VO}_4:0.03\text{Ho}^{3+}$ phosphor

| [$S'L'J'$] manifold | A_{T} (s ⁻¹) | τ_{rad} (μs) |
|-----------------------------|-----------------------------------|---------------------------------------|
| ³ H ₅ | 1497 | 668 |
| ⁵ G ₆ | 1592 | 628 |
| ³ K ₈ | 159 | 6297 |
| ⁵ F ₂ | 867 | 1153 |
| ⁵ F ₃ | 1060 | 943 |
| ⁵ F ₄ | 1082 | 924 |
| ⁵ F ₅ | 542 | 1845 |

| Transition | β |
|---|---------|
| ³ H ₅ → ⁵ I ₈ | 0.423 |
| ⁵ G ₆ → ⁵ I ₈ | 0.752 |
| ³ K ₈ → ⁵ I ₈ | 0.880 |
| ⁵ F ₂ → ⁵ I ₈ | 0.566 |
| ⁵ F ₃ → ⁵ I ₈ | 0.524 |
| ⁵ F ₄ → ⁵ I ₈ | 0.816 |
| ⁵ F ₅ → ⁵ I ₈ | 0.775 |

Under UV excitation of 310 nm, the PL emission spectra of $\text{Y}_{1-x}\text{VO}_4:x\text{Ho}^{3+}$ phosphors are measured from the 450 nm to 700 nm wavelength region, and the results are represented in Fig. 7(b). The emission spectra show intense green emissions around 541, 546, and 551 nm, which are attributed to the (⁵S₂ + ⁵F₄) → ⁵I₈ transitions of Ho^{3+} ion. A few small emission peaks are

observed around 475 nm (⁵F₂ → ⁵I₈), 485 nm (⁵F₃ → ⁵I₈), 526 nm (⁵G₅ → ⁵I₇), and 650 and 661 nm (⁵F₅ → ⁵I₈) wavelengths.^{63,64} Fig. 8 shows the energy level diagram of Ho^{3+} ion with possible transitions. Under UV excitation at 310 nm, the excitation energy is first absorbed by VO₄³⁻ group, which excites the electrons from the filled oxygen 2p levels in the valence band to the empty vanadium 3d levels of the conduction band. The emission from the VO₄³⁻ group is not observed in this phosphor. Instead of emission from the VO₄³⁻ group, the resonant energy transfer takes place from the VO₄³⁻ group to the ⁵G₄ level of the Ho^{3+} ion. From ⁵G₄ level, the non-radiative transitions take place to lower lying levels of Ho^{3+} ion and due to this, various emissions take place at different wavelengths as indicated in Fig. 8.

In general, the doping concentration could affect the efficiency or performance of the phosphor, so it is necessary to analyze the effect of Ho^{3+} ion concentration on the PL intensity. In the present analysis, the concentration of Ho^{3+} ion in the YVO₄ host is varied from 0.01 to 0.11 mol, and the resultant PL intensity as a function of Ho^{3+} ion concentration is shown in Fig. 9. The PL intensity is maximum at $x = 0.03$, and it then decreases due to the effect of concentration quenching. This result suggests that the optimum concentration of Ho^{3+} ion in the YVO₄ host is 0.03 mol. The concentration quenching depends on the critical distance (R_{C}) between the activator ion and the quenching site. According to Blasse, R_{C} can be calculated using the following expression:⁶⁵

$$R_{\text{C}} = 2 \left(\frac{3V}{4\pi X_{\text{C}}N} \right)^{1/3} \quad (10)$$

here, V = volume of unit cell, X_{C} = optimal concentration of Ho^{3+} ions, and N = number of dopant sites available in the unit cell. In our case, $V = 318.82 \text{ \AA}^3$, $X_{\text{C}} = 0.03$, and $N = 4$. From eqn (10), this equates to a critical distance of 17.18 Å, which is greater than 5 Å, thus indicating a smaller chance of energy transfer *via* exchange interaction. Therefore, the process of energy transfer occurs *via* electric multipolar interaction, which causes concentration quenching of Ho^{3+} ion in the prepared phosphors.

The peak stimulated emission cross-section (σ_{p}) for the (⁵S₂ + ⁵F₄) → ⁵I₈ transition of Ho^{3+} ion for the optimum



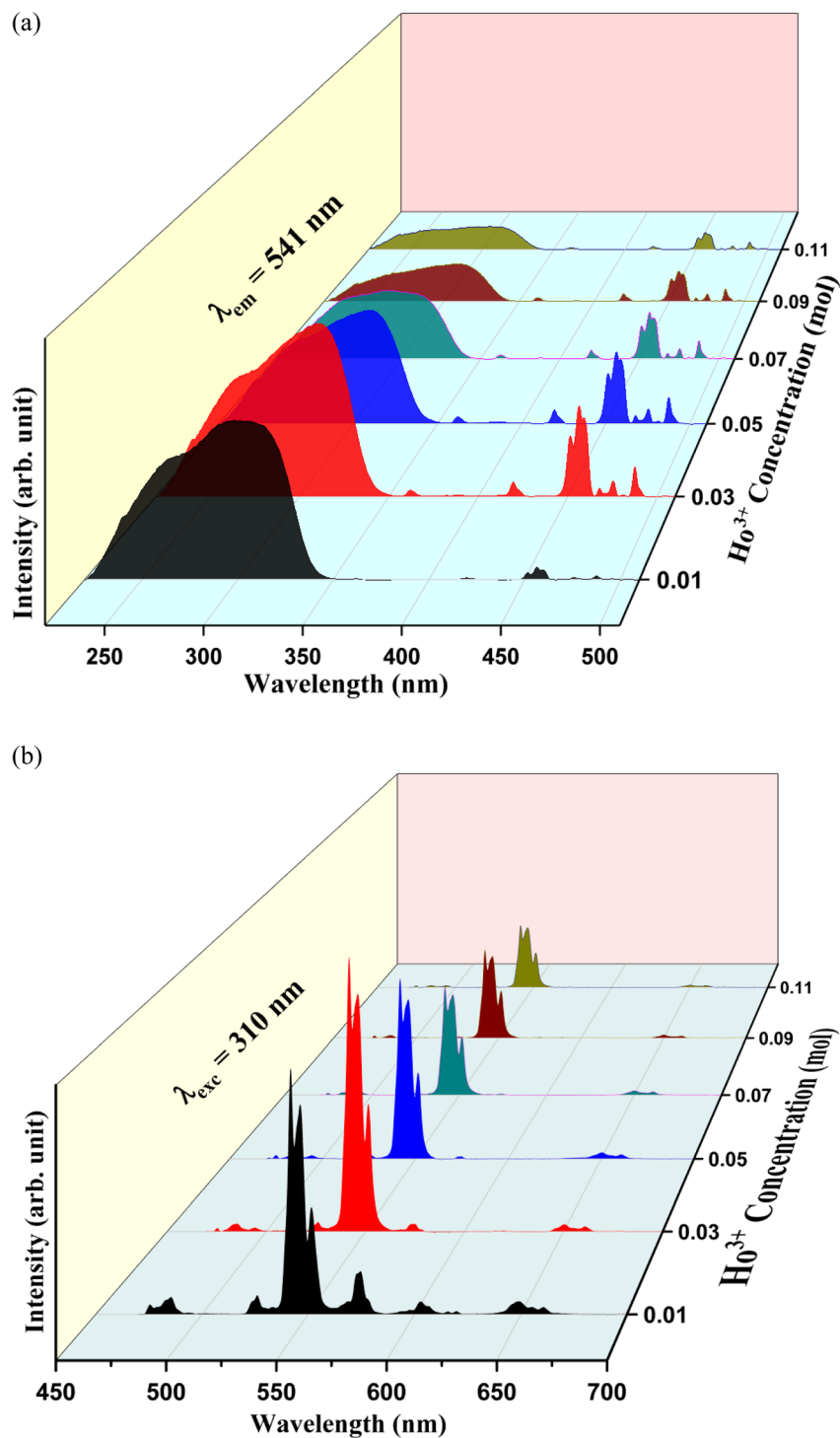


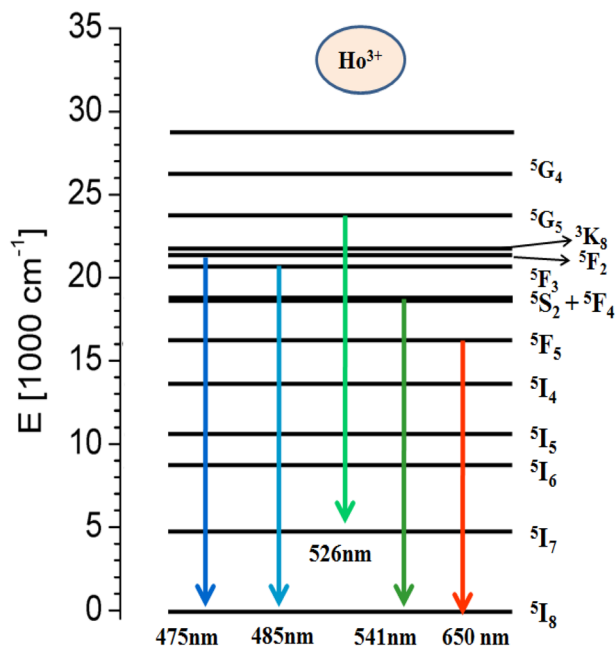
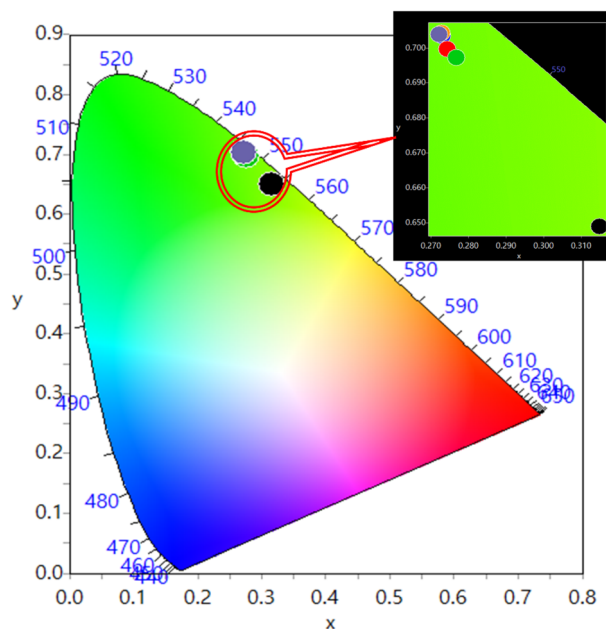
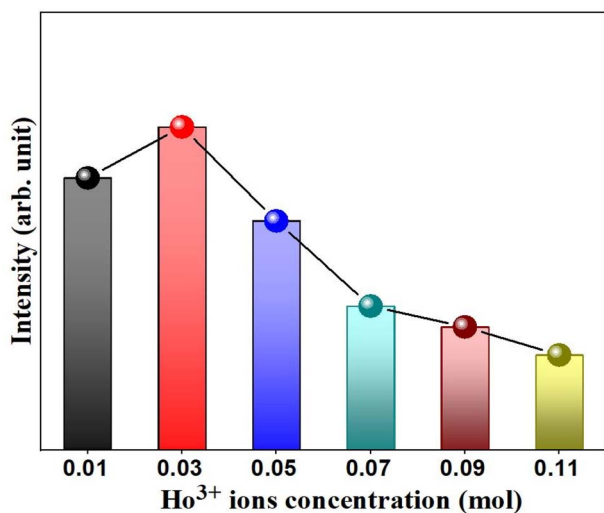
Fig. 7 Photoluminescence spectra of $Y_{1-x}VO_4:xHo^{3+}$ phosphors: (a) excitation spectra ($\lambda_{emi} = 541$ nm) and (b) emission spectra ($\lambda_{exc} = 310$ nm).

($Y_{0.97}VO_4:0.03Ho^{3+}$) phosphor is also obtained from the following relation⁵³

$$\sigma_p(\lambda) = \frac{\lambda_p^4}{8\pi cn^2 \Delta\lambda_{eff}} \cdot A_{rad} \quad (11)$$

Here, λ_p and $\Delta\lambda_{eff}$ are the peak wavelength and effective line width of the emission band, respectively. The estimated $\Delta\lambda_{eff}$ and $\sigma_p(\lambda)$ are 6.33 nm and 3.22×10^{-21} cm², respectively for the ($^5S_2 + ^5F_4$) \rightarrow 5I_8 transition of Ho^{3+} ions in YVO_4 phosphor. The values of $\sigma_p(\lambda)$ (3.22×10^{-21} cm²) and β (0.816) for the green



Fig. 8 Schematic energy level diagram of Ho³⁺ ion.Fig. 10 CIE diagram for Y_{1-x}VO₄:xHo³⁺ phosphors.Fig. 9 Variation of emission intensity (I_{541nm}) as a function of Ho³⁺ concentration in the Y_{1-x}VO₄:xHo³⁺ phosphor.

emission of Ho³⁺:YVO₄ are larger than Y₂O₃:Ho³⁺ ($\sigma_p(\lambda) = 1.32 \times 10^{-21} \text{ cm}^2$; $\beta = 0.65$),⁵⁸ which suggests that the Ho³⁺:YVO₄ phosphor is a desirable optical material for low threshold and high gain applications. These remarkable results provide information on energy transfer from VO₄³⁻ group to Ho³⁺ ions.

The CIE (Commission International de l'Eclairage) chromaticity coordinates of the prepared Y_{1-x}VO₄:xHo³⁺ phosphor materials are represented in Fig. 10. The results show that the CIE coordinates fall in the green region.^{66,67} The color coordinates and color purity of the prepared phosphors are summarized in Table 5.

Table 5 Commission International de l'Eclairage (CIE) color coordinates and color purity for the Y_{1-x}VO₄:xHo³⁺ phosphors using PL emission at $\lambda_{exc} = 310 \text{ nm}$

| Y _{1-x} VO ₄ :xHo ³⁺ | $\lambda_{exc} = 310 \text{ nm}$ | | Color purity (%) |
|---|----------------------------------|-------|------------------|
| | x | y | |
| x = 0.01 | 0.315 | 0.649 | 84.27(●) |
| x = 0.03 | 0.273 | 0.704 | 98.64(●) |
| x = 0.05 | 0.274 | 0.700 | 97.61(●) |
| x = 0.07 | 0.276 | 0.700 | 97.56(●) |
| x = 0.09 | 0.277 | 0.697 | 96.78(●) |
| x = 0.11 | 0.282 | 0.699 | 97.18(●) |

4. Conclusions

In summary, we report herein the spectroscopic properties of a homogenous series of Y_{1-x}VO₄:xHo³⁺ phosphor materials synthesized using the sol-gel synthesis procedure. SEM analysis shows the irregular particles size of the phosphor. The preparation of a single-phase compound was confirmed by the XRD patterns. The optical transitions of Ho³⁺ ions are identified through diffuse reflectance spectrum. Using these absorption bands, the oscillator strength of the bands (f_{exp} & f_{cal}), the Judd-Ofelt parameters (Ω_λ , $\lambda = 2, 4, \& 6$), total radiative transition probabilities (A_T), radiative lifetimes (τ_{rad}), and branching ratios (β) for the transition of Ho³⁺ ions in Y_{0.97}VO₄:0.03Ho³⁺ phosphor are reported. The energy conversion; and optical direct and indirect bandgaps are observed for YVO₄ phosphor doped with Ho³⁺ ions. In this approach, the energy transfer to the Ho³⁺ ions supports the results of the spectroscopic analyses. The phosphor exhibited a strong excitation band in the UV region at 310 nm while monitoring emission at 541 nm. Upon 310 nm



excitation, all the synthesized phosphors showed intense PL emission in the green region. Concentration quenching of Ho^{3+} ion was observed after 0.03 mol and this was mainly attributed to the electric multipolar interaction process. The $\text{Y}_{0.97}\text{VO}_4:0.03\text{Ho}^{3+}$ phosphor showed good emissive properties with very high color purity, suggesting that this material would be useful for green emitting devices.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This work was supported by the National Research Foundation of Korea (NRF) grant funded by the Korea government (MSIT) (No. 2021R1A2C1092509).

References

- V. Panchal, S. Lopez-Moreno, D. Sanatamaria-Perez, D. Errandonea, F. J. Manjon, P. Rodriguez-Hernandez, A. Munoz, S. N. Achary and A. K. Tyagi, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2011, **84**, 02411.
- V. Panchal, D. Errandonea, A. Segura, P. Rodriguez-Hernandez, A. Munoz, S. Lopez-Moreno and M. Bettinelli, *J. Appl. Phys.*, 2011, **110**, 43723.
- N. Deligne, V. Gonze, D. Bayot and M. Devillers, *Eur. J. Inorg. Chem.*, 2008, **6**, 896–902.
- E. V. Tsipis, V. V. Kharton, N. P. Vyshatko, A. L. Shaula and J. R. Frade, *J. Solid State Chem.*, 2003, **176**, 47–56.
- Z. Xu, X. Kang, C. Li, Z. Hou, C. Zhang, D. Yang, G. Li and J. Lin, *Inorg. Chem.*, 2010, **49**, 6706.
- Z. Y. Hou, P. P. Yang, C. X. Li, L. L. Wang, H. Z. Lian, Z. W. Quan and J. Lin, *Chem. Mater.*, 2008, **20**, 6686.
- F. He, P. Yang, N. Niu, W. Wang, S. Gai, D. Wang and J. Lin, *J. Colloid Interface Sci.*, 2010, **343**, 71.
- P. Huang, D. Chen and Y. Wang, *J. Alloys Compd.*, 2011, **509**, 3375.
- L. Xie, H. Song, Y. Wang, W. Xu, X. Bai and B. Dong, *J. Phys. Chem. C*, 2010, **114**, 9975.
- L. Li, M. Zhao, W. Tong, X. Guan, G. Li and L. Yang, *Nanotechnology*, 2010, **21**, 195601.
- M. Yu, J. Lin and J. Fang, *Chem. Mater.*, 2005, **17**, 1783–1791.
- A. Bao, H. Lai, Y. Yang, Z. Liu, C. Tao and H. Yang, *J. Nanopart. Res.*, 2010, **12**, 635–643.
- E. A. Maunders and L. G. DeShazer, *J. Opt. Soc. Am.*, 1971, **61**, 684.
- F. S. Ermeneux, R. Moncorge, P. Kabro, J. A. Capobianco, M. Bettinelli and E. Cavalli, *Adv. Solid State Lasers*, OSA, Washington, DC, 1996, p. SM9.
- J. Sun, J. Zhu, X. Liu and H. Du, *Mater. Res. Bull.*, 2013, **48**, 2175–2179.
- J. A. Coppabianco, P. Kabro, F. S. Ermeneux, R. Moncorge, M. Bettinelli and E. Cavalli, *Chem. Phys.*, 1997, **214**, 329–340.
- M. Mahata, S. Tiwari, S. Mukherjee, K. Kumar and V. Rai, *J. Opt. Soc. Am. B*, 2014, **31**, 1814–1821.
- J. E. Bernard and A. J. Alcock, *Opt. Lett.*, 1993, **18**, 968.
- G. C. Bowkett, G. W. Baxter, D. J. Booth, T. Taira, H. Teranishi and T. Kobayashi, *Opt. Lett.*, 1994, **19**, 957.
- D. Shen, A. Liu, J. Song and K. Ueda, *Appl. Opt.*, 1998, **37**, 7785.
- X. Li, H. Xu, R. Yan, Y. Jiang, R. Fan, Z. Dong and D. Chen, *Optik*, 2021, **228**, 165789.
- A. K. Levine and F. C. Palilla, *Appl. Phys. Lett.*, 1964, **5**, 118–120.
- A. Brill, W. L. Wanmaker and J. Broos, *J. Chem. Phys.*, 1965, **43**, 311.
- L. R. Singh and R. S. Ningthoujam, *J. Appl. Phys.*, 2010, **107**, 104304–104306.
- W. M. Yen, S. Shionoya and H. Yamamoto, *Phosphor Handbook*, CRC Press, Boca-Raton, 2nd edn, 1999.
- C. Hsu and R. C. Powell, *J. Lumin.*, 1975, **10**, 273–293.
- M. Wu, S. Choi and H. K. Jung, *Mater. Res. Bull.*, 2016, **78**, 20–25.
- U. Rambabu, D. P. Amalnerkar, B. B. Kale and S. Buddhudu, *Mater. Res. Bull.*, 2000, **35**, 929–936.
- L. Shirmane, C. Feldmann and V. Pankratov, *Phys. B*, 2017, **504**, 80–85.
- S. M. Rafiaei and M. Shokouhimehr, *Mater. Chem. Phys.*, 2019, **229**, 431–436.
- K. E. Foka, B. F. Dejene and H. C. Swart, *Phys. B*, 2016, **480**, 95–99.
- Y. Liu, H. Xiong, N. Zhang, Z. Leng, R. Li and S. Gan, *J. Alloys Compd.*, 2015, **653**, 126–134.
- Z. Xu, X. Kang, C. Li, Z. Hou, C. Zhang, D. Yang, G. Li and J. Lin, *Inorg. Chem.*, 2010, **49**, 6706–6715.
- X. Y. Huang, J. X. Wang, D. C. Yu, S. Ye, Q. Y. Zhang and X. W. Sun, *J. Appl. Phys.*, 2011, **109**, 113526.
- V. A. Medvedev, D. V. Mamonova, I. E. Kolesnikov, A. R. Khokhlova, M. D. Mikhailov and A. A. Manshina, *Inorg. Chem. Commun.*, 2020, **118**, 107990.
- H. Zhou, W. Gao, P. Cai, B. Zhang and S. Li, *Solid State Sci.*, 2020, **104**, 106283.
- Y. H. Li and G. Y. Hong, *J. Solid State Chem.*, 2005, **175**, 645–649.
- S. Ekambaram and K. C. Patil, *J. Alloys Compd.*, 1995, **217**, 104–107.
- A. Dwivedi, E. Rai, D. Kumar and S. B. Rai, *ACS Omega*, 2019, **4**, 6903–6913.
- M. Yu, J. Lin, Z. Wang, J. Fu, S. Wang, H. J. Zhang and Y. C. Han, *Chem. Mater.*, 2002, **14**, 2224–2231.
- L. D. Sun, Y. X. Zhang, J. Zhang, C. H. Yan, C. S. Liao and Y. Q. Lu, *Solid State Commun.*, 2002, **124**, 35–38.
- G. Jia, Y. Song, M. Yang, Y. Huang, L. Zhang and H. You, *Opt. Mater.*, 2009, **31**, 1032–1037.
- L. Zhu, J. Y. Li, Q. Li, X. D. Liu, J. Meng and X. Q. Cao, *Nanotechnology*, 2007, **18**, 055604–055609.
- Y. H. Zhou and J. Lin, *Opt. Mater.*, 2005, **27**, 1426–1432.
- M. R. Dolgos, A. M. Paraskos, M. W. Stoltzfus, S. C. Yarnell and P. M. Woodward, *J. Solid State Chem.*, 2009, **182**, 1964–1971.
- W. O. Milligan and L. W. Vernon, *J. Phys. Chem. A*, 1952, **56**, 145–147.



- 47 Y. Sun, H. Liu, X. Wang, X. Kon and H. Zhang, *Chem. Mater.*, 2006, **18**, 2726–2732.
- 48 C. Shivakumara, R. Saraf and P. Halappa, *Dyes Pigment.*, 2016, **126**, 154–164.
- 49 B. R. Judd, *Phys. Rev.*, 1962, **127**, 750.
- 50 G. S. Ofelt, *J. Chem. Phys.*, 1962, **37**, 511.
- 51 A. A. Kaminskii, *Crystalline Lasers*, CRC Press, 1996.
- 52 W. T. Carnall, H. Crosswhite and H. M. Crosswhite, *Energy Level Structure and Transition Probabilities of the Trivalent Lanthanides in LaF₃*, Argonne National Laboratory, Argonne, IL, 1975.
- 53 M. Seshadri, E. F. Chillcce, J. D. Marconi, F. A. Sigoli, Y. C. Ratnakaram and L. C. Barbosa, *J. Non-Cryst. Solids*, 2014, **402**, 141.
- 54 Ş. Georgescu, A. Ştefan, O. Toma and A.-M. Voiculescu, *J. Lumin.*, 2015, **162**, 174–179.
- 55 M. Kaczkan and M. Malinowski, *Materials*, 2021, **14**, 3831.
- 56 M. Malinowski, Z. Frukacz, M. Szuflińska, A. Wnuk and M. Kaczkan, *J. Alloys Compd.*, 2000, **300–301**, 389–394.
- 57 M. Kaczkan, I. Pracka and M. Malinowski, *Opt. Mater.*, 2004, **25**, 345–352.
- 58 V. Singh, V. K. Rai, B. Voss, M. Haase, R. P. S. Chakradhar, D. T. Naidu and S. H. Kim, *Spectrochim. Acta, Part A*, 2013, **109**, 206–212.
- 59 B. M. Walsh, G. W. Grew and N. P. Barnes, *J. Phys.: Condens. Matter*, 2005, **17**, 7643–7665.
- 60 Q. Dong, G. Zhao, J. Chen, Y. Ding, B. Yao and Z. Yu, *Opt. Mater.*, 2010, **32**, 873–877.
- 61 S. R. Bullock, B. R. Reddy, P. Venkateswarlu and S. K. N. Stevenson, *J. Opt. Soc. Am. B*, 1997, **14**, 553–559.
- 62 A. Huignard, V. Buissette, A. Franville, T. Gacoin and J. Boilot, *J. Phys. Chem. B*, 2003, **107**, 6754–6759.
- 63 I. E. Kolesnikov, A. A. Kalinichev, M. A. Kurochkin, D. V. Mamonova, E. Y. Kolesnikov and E. Lahderanta, *J. Phys. Chem. C*, 2019, **123**, 5136–5143.
- 64 V. Singha, G. Lakshminarayana, A. Wagh and N. Singh, *Optik*, 2020, **207**, 164284.
- 65 G. Blasse, *Phys. Lett. A*, 1968, **28**, 444–445.
- 66 Monika, R. S. Yadav, A. Rai and S. B. Rai, *Sci. Rep.*, 2021, **11**, 4148.
- 67 P. Tadge, I. R. Martín, S. B. Rai, S. Sapra, T. M. Chen, V. Lavín, R. S. Yadav and S. Ray, *J. Lumin.*, 2022, **252**, 119261.

